

Electronic structure of BiFeO₃ in different crystal phases

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Multiferroic BiFeO₃ under normal conditions crystallizes in the rhombohedral $R\bar{3}c$ space group. However doping can change its crystal structure to e.g. $Pn\bar{2}_1a$ (with Gd [1]), $Pnma$ (with Gd [1], Y [2]) or Cm (with Ga [3]). We present the electronic structure calculations of undoped BiFeO₃ in these structures within DFT+U approach. Our structural calculations are in good agreement with previous calculations [4]. Our results show that BiFeO₃ favors G-AFM ordering for $R\bar{3}c$, $Pn\bar{2}_1a$, $Pnma$ structures and C-AFM ordering for Cm phase. In all structures BiFeO₃ is a semiconductor with the band gap: 2.26 eV ($R\bar{3}c$), 1.91 eV ($Pnma$), 1.99 eV ($Pn\bar{2}_1a$), 2.09 eV (Cm).

References:

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This work was supported by the National Science Centre (Poland) through grant no. DEC-2011/01/B/ST3/02212